

# BLP7G22-10

## LDMOS driver transistor

Rev. 1 — 13 February 2012

Objective data sheet

## 1. Product profile

### 1.1 General description

The BLP7G22-10 is low power driver using NXP's state of the art GEN7 LDMOS technology. This device is perfectly suited as general purpose driver in the frequency range from 700 MHz to 2200 MHz.

**Table 1. Application performance (multiple frequencies)**

Typical RF performance at  $T_{case} = 25\text{ }^{\circ}\text{C}$ ;  $I_{DQ} = 50\text{ mA}$ ; in a class-AB application circuit.

| Test signal      | f<br>(MHz) | $I_{DQ}$<br>(mA) | $V_{DS}$<br>(V) | $P_{L(AV)}$<br>(W) | $G_p$<br>(dB) | $\eta_D$<br>(%) | IMD3<br>(dBc) | ACPR<br>(dBc)      |
|------------------|------------|------------------|-----------------|--------------------|---------------|-----------------|---------------|--------------------|
| 1-carrier W-CDMA | 748        | 110              | 28              | 0.7                | 27            | 16              | –             | –45 <sup>[1]</sup> |
|                  | 748        | 110              | 28              | 2                  | 27            | 26              | –             | –43                |
| 2-carrier W-CDMA | 2140       | 90               | 28              | 0.7                | 17            | 16              | –46           | –48 <sup>[2]</sup> |
|                  | 2140       | 90               | 28              | 2                  | 17            | 26              | –40           | –43                |

[1] Single carrier; Test signal: 3GPP; test model 1; 64 DPCH; PAR = 8.7 dB at 0.01 % probability on CCDF per carrier.

[2] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF per carrier. Carrier spacing 10 MHz

### 1.2 Features and benefits

- Typical 1-carrier W-CDMA performance at frequency 748 MHz:
  - ◆ Average output power = 0.7 W
  - ◆ Power gain = 27 dB
  - ◆ Efficiency = 16 %
  - ◆ Ruggedness at least 10 : 1,  $P_L = 10\text{ W}$
- Typical 2-carrier W-CDMA performance at frequency 2140 MHz:
  - ◆ Average output power = 0.7 W
  - ◆ Power gain = 17 dB
  - ◆ Efficiency = 16 %
  - ◆ Ruggedness at least 10 : 1,  $P_L = 10\text{ W}$
- Integrated ESD protection
- Excellent thermal stability
- High power gain
- Designed for broadband operation (700 MHz to 2200 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

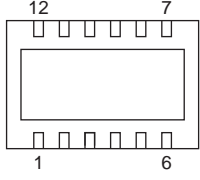
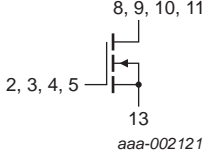


### 1.3 Applications

- GSM/EDGE
- TDS/CDMA
- W-CDMA

## 2. Pinning information

Table 2. Pinning

| Pin          | Description | Simplified outline   | Graphic symbol  |
|--------------|-------------|--|---|
| 1, 6, 7, 12  | n.c.        |  <p>Transparent top view</p> |  <p>aaa-002121</p> |
| 2, 3, 4, 5   | gate        |  |   |
| 8, 9, 10, 11 | drain       |  |   |
| 13           | source      |  |   |

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |  |           |
|-------------|---------|--|-----------|
|             | Name    | Description  | Version   |
| BLP7G22-10  | HVSON12 | plastic thermal enhanced very thin small outline package; no leads; 12 terminals; body 4 x 6 x 0.85 mm | SOT1179-1 |

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter            | Conditions | Min  | Max  | Unit |
|-----------|----------------------|------------|------|------|------|
| $V_{DS}$  | drain-source voltage |            | -    | 65   | V    |
| $V_{GS}$  | gate-source voltage  |            | -0.5 | +13  | V    |
| $T_{stg}$ | storage temperature  |            | -65  | +150 | °C   |
| $T_j$     | junction temperature |            | -    | 150  | °C   |

## 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol        | Parameter   | Conditions                                  | Typ | Unit |
|---------------|---|---|-----|------|
| $Z_{th(j-c)}$ | transient thermal impedance from junction to case | $T_{case} = 70\text{ °C}; P_L = 2\text{ W}$ | 3.0 | K/W  |

## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ }^\circ\text{C}$ ; unless otherwise specified.

| Symbol        | Parameter                        | Conditions  | Min  | Typ  | Max  | Unit             |
|---------------|----------------------------------|---|------|------|------|------------------|
| $V_{(BR)DSS}$ | drain-source breakdown voltage   | $V_{GS} = 0\text{ V}$ ; $I_D = 0.18\text{ mA}$                    | 65   | -    | -    | V                |
| $V_{GS(th)}$  | gate-source threshold voltage    | $V_{DS} = 10\text{ V}$ ; $I_D = 18\text{ mA}$                     | 1.4  | <td> | 2.4  | V                |
| $V_{GSq}$     | gate-source quiescent voltage    | $V_{DS} = 28\text{ V}$ ;<br>$I_D = \text{<td> mA}$                | <td> | <td> | <td> | V                |
| $I_{DSS}$     | drain leakage current            | $V_{GS} = 0\text{ V}$ ; $V_{DS} = 28\text{ V}$                    | -    | -    | 2.8  | $\mu\text{A}$    |
| $I_{DSX}$     | drain cut-off current            | $V_{GS} = V_{GS(th)} + 3.75\text{ V}$ ;<br>$V_{DS} = 10\text{ V}$ | -    | 3.5  | -    | A                |
| $I_{GSS}$     | gate leakage current             | $V_{GS} = 11\text{ V}$ ; $V_{DS} = 0\text{ V}$                    | -    | -    | 280  | nA               |
| $g_{fs}$      | forward transconductance         | $V_{DS} = 10\text{ V}$ ; $I_D = 18\text{ mA}$                     | 107  | 160  | 210  | mS               |
| $R_{DS(on)}$  | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75\text{ V}$ ;<br>$I_D = 630\text{ mA}$  | 0.32 | 0.79 | 1.26 | $\text{m}\Omega$ |

**Table 7. RF characteristics**

Test signal: 1-tone pulsed;  $t_p = 20\text{ }\mu\text{s}$ ;  $\delta = 10\%$ ;  $f_1 = 2110\text{ MHz}$ ;  $f_2 = 2170\text{ MHz}$ ; RF performance at  $V_{DS} = 28\text{ V}$ ;  $I_{Dq} = \text{<td> mA}$ ;  $T_{case} = 25\text{ }^\circ\text{C}$ ; unless otherwise specified, in a production circuit.

| Symbol    | Parameter         | Conditions                                 | Min  | Typ  | Max  | Unit |
|-----------|-------------------|--|------|------|------|------|
| $G_p$     | power gain        | 1-tone pulsed;<br>$P_{L(AV)} = 2\text{ W}$ | <td> | 17   | <td> | dB   |
| $\eta_D$  | drain efficiency  | $P_{L(AV)} = 2\text{ W}$                   | <td> | 25   | -    | %    |
| $RL_{in}$ | input return loss | $P_{L(AV)} = 2\text{ W}$                   | -    | <td> | <td> | dB   |

### 6.1 Ruggedness in class-AB operation

The BLP7G22-10 is capable of withstanding a load mismatch corresponding to  $V_{SWR} = 10 : 1$  through all phases under the following conditions:  $V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 110\text{ mA}$ ;  $P_L = 10\text{ W}$ ; frequency from 700 MHz to 2200 MHz.

## 7. Package outline

HVSON12: plastic thermal enhanced very thin small outline package; no leads;  
12 terminals; body 4 x 6 x 0.85 mm

SOT1179-1

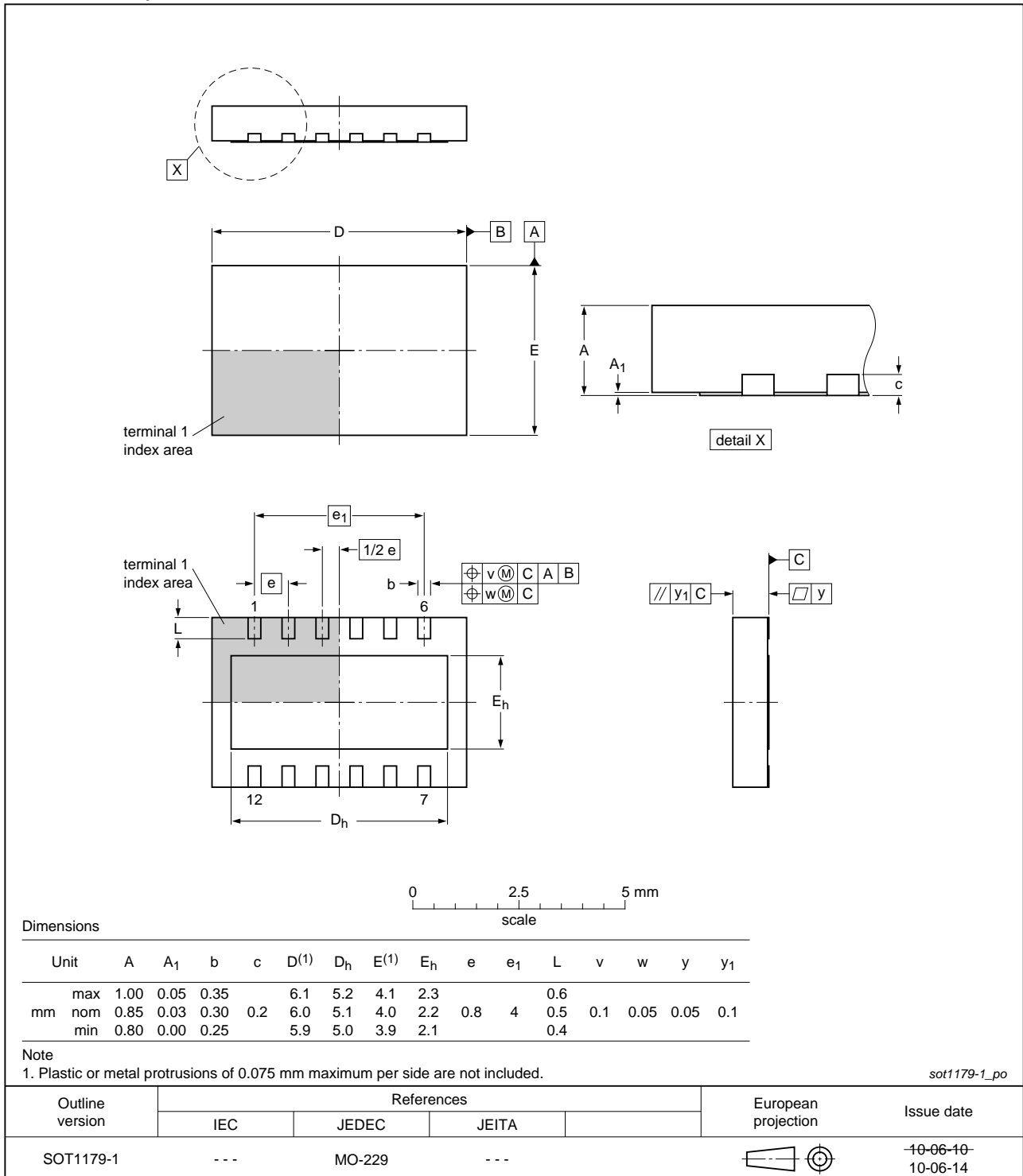


Fig 1. Package outline SOT1179-1

## 8. Handling information

### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

## 9. Abbreviations

**Table 8. Abbreviations**

| Acronym | Description                                    |
|---------|--|
| 3GPP    | Third Generation Partnership Project           |
| CCDF    | Complementary Cumulative Distribution Function |
| CDMA    | Code Division Multiple Access                  |
| DPCH    | Dedicated Physical CHannel                     |
| EDGE    | Enhanced Data rates for GSM Evolution          |
| GEN7    | seventh-generation                             |
| GSM     | Global System for Mobile Communication         |
| LDMOS   | Laterally Diffused Metal-Oxide Semiconductor   |
| PAR     | Peak-to-Average power Ratio                    |
| RF      | Radio Frequency                                |
| TDS     | Time Division Synchronous                      |
| VSWR    | Voltage Standing-Wave Ratio                    |
| W-CDMA  | Wideband Code Division Multiple Access         |

## 10. Revision history

**Table 9. Revision history**

| Document ID    | Release date | Data sheet status    | Change notice | Supersedes |
|----------------|--------------|----------------------|---------------|------------|
| BLP7G22-10 v.1 | 20120213     | Objective data sheet | -             | -          |

## 11. Legal information

### 11.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

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## 13. Contents

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|           |  |          |
|-----------|--|----------|
| <b>1</b>  | <b>Product profile</b> . . . . .           | <b>1</b> |
| 1.1       | General description . . . . .              | 1        |
| 1.2       | Features and benefits . . . . .            | 1        |
| 1.3       | Applications . . . . .                     | 2        |
| <b>2</b>  | <b>Pinning information</b> . . . . .       | <b>2</b> |
| <b>3</b>  | <b>Ordering information</b> . . . . .      | <b>2</b> |
| <b>4</b>  | <b>Limiting values</b> . . . . .           | <b>2</b> |
| <b>5</b>  | <b>Thermal characteristics</b> . . . . .   | <b>2</b> |
| <b>6</b>  | <b>Characteristics</b> . . . . .           | <b>3</b> |
| 6.1       | Ruggedness in class-AB operation . . . . . | 3        |
| <b>7</b>  | <b>Package outline</b> . . . . .           | <b>4</b> |
| <b>8</b>  | <b>Handling information</b> . . . . .      | <b>5</b> |
| <b>9</b>  | <b>Abbreviations</b> . . . . .             | <b>5</b> |
| <b>10</b> | <b>Revision history</b> . . . . .          | <b>5</b> |
| <b>11</b> | <b>Legal information</b> . . . . .         | <b>6</b> |
| 11.1      | Data sheet status . . . . .                | 6        |
| 11.2      | Definitions . . . . .                      | 6        |
| 11.3      | Disclaimers . . . . .                      | 6        |
| 11.4      | Trademarks . . . . .                       | 7        |
| <b>12</b> | <b>Contact information</b> . . . . .       | <b>7</b> |
| <b>13</b> | <b>Contents</b> . . . . .                  | <b>8</b> |

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Date of release: 13 February 2012

Document identifier: BLP7G22-10